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Vishay Semiconductors

## Thyristor High Voltage, Phase Control SCR, 40 A



PRIMARY CHARACTERISTICS					
I <sub>T(AV)</sub> 35 A					
V <sub>DRM</sub> /V <sub>RRM</sub>	1600 V				
$V_{TM}$	1.45 V				
I <sub>GT</sub>	150 mA				
$T_J$	-40 °C to +125 °C				
Package	TO-247AC 3L				
Circuit configuration	Single SCR				

#### **FEATURES**

- High voltage (up to 1600 V)
- Designed and qualified according to JEDEC®-JESD 47
- 125 °C max. operating junction temperature
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



### **APPLICATIONS**

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

#### **DESCRIPTION**

The VS-40TPS16... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I <sub>T(AV)</sub>	Sinusoidal waveform	35	^		
I <sub>RMS</sub>		55	A		
V <sub>RRM</sub> /V <sub>DRM</sub>		1600	V		
I <sub>TSM</sub>		500	A		
V <sub>T</sub>	40 A, T <sub>J</sub> = 25 °C	1.45	V		
dV/dt		1000	V/µs		
dl/dt		100	A/µs		
T <sub>J</sub>		-40 to +125	°C		

VOLTAGE RATINGS							
PART NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA				
VS-40TPS16-M3	1600	1700	10				



ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	TEST CONDITIONS			
Maximum average on-state current	I <sub>T(AV)</sub>	T <sub>C</sub> = 79 °C, 180° conduction half sine wave	,	35		
Maximum continuous RMS on-state current as AC switch	I <sub>T(RMS)</sub>			55	A	
Maximum peak, one-cycle	L	10 ms sine pulse, rated $V_{\mbox{\scriptsize RRM}}$ applied		420		
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no voltage reapplied		500		
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	Initial $T_J = T_{II}$ maximum	880	A <sup>2</sup> s	
Maximum i-t for fusing	I-l	10 ms sine pulse, no voltage reapplied	Timaximam	1250		
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied		12 500	A²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>		1.02	V		
High level value of threshold voltage	V <sub>T(TO)2</sub>	T <sub>J</sub> = 125 °C		1.23	\ \	
Low level value of on-state slope resistance	r <sub>t1</sub>	11 - 123 0		9.74	mΩ	
High level value of on-state slope resistance	r <sub>t2</sub>			7.50	1115.2	
Maximum peak on-state voltage	$V_{TM}$	110 A, T <sub>J</sub> = 25 °C		1.85	V	
Maximum rate of rise of turned-on current	dl/dt	$T_J = 25  ^{\circ}C$		100	A/μs	
Maximum holding current	IH	Anode supply = 6 V, resistive load, initial I <sub>T</sub> = 1 A, T <sub>J</sub> = 25 °C		200		
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T <sub>J</sub> = 25 °C		300	mA	
Maximum reverse and direct leakage current	1 /1	$T_J = 25  ^{\circ}C$	V <sub>R</sub> = rated V <sub>RRM</sub> /V <sub>DRM</sub>		IIIA	
	I <sub>RRM</sub> /I <sub>DRM</sub>	$T_J = 125  ^{\circ}\text{C}$				
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80 % $V_{DRM}$ , $R_g$ - $k$ = open		1000	V/µs	

TRIGGERING						
PARAMETER	SYMBOL	TE	EST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	$P_{GM}$			10	W	
Maximum average gate power	P <sub>G(AV)</sub>			2.5	VV	
Maximum peak gate current	I <sub>GM</sub>			2.5	Α	
Maximum peak negative gate voltage	- V <sub>GM</sub>			10		
Maximum required DC gate	V <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Anode supply = 6 V resistive load	4.0	V mA	
Maximum required DC gate voltage to trigger		T <sub>J</sub> = 25 °C		2.5		
voltage to angger		T <sub>J</sub> = 125 °C		1.7		
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Anode supply = 6 V resistive load	270		
Maximum required DC gate current to trigger		T <sub>J</sub> = 25 °C		150		
waximum required DO gate current to trigger		T <sub>J</sub> = 125 °C		80		
		T <sub>J</sub> = 25 °C, for 40TPS08A		40		
Maximum DC gate voltage not to trigger	$V_{GD}$	T = 195 °C V = reted value		0.25	٧	
Maximum DC gate current not to trigger	$I_{GD}$	T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = rated value		6	mA	



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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to 125	°C
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	0.6	
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W
Maximum thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2	
Approximate weight	A			6	g
Approximate weight				0.21	OZ.
Mounting torque	minimum				kgf · cm
woulding torque	maximum			12 (10)	(lbf $\cdot$ in)
Marking device			Case style TO-247AC 3L	40TF	PS16

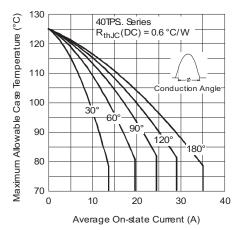


Fig. 1 - Current Rating Characteristics

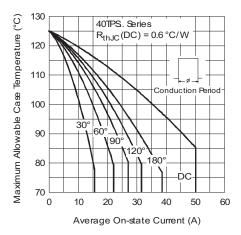


Fig. 2 - Current Rating Characteristics

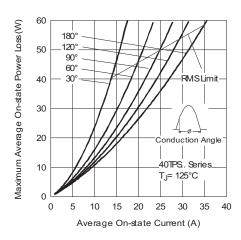


Fig. 3 - On-State Power Loss Characteristics

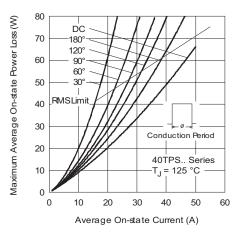


Fig. 4 - On-State Power Loss Characteristics

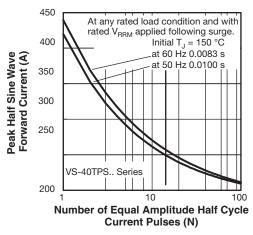


Fig. 5 - Maximum Non-Repetitive Surge Current

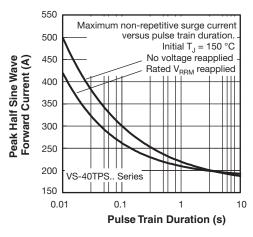


Fig. 6 - Maximum Non-Repetitive Surge Current

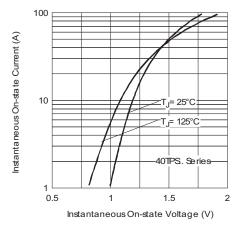


Fig. 7 - On-State Voltage Drop Characteristics

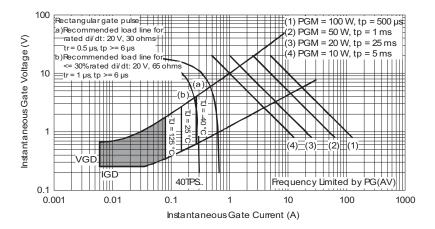


Fig. 8 - Gate Characteristics

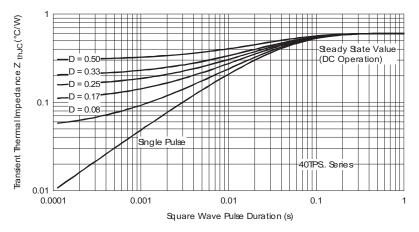
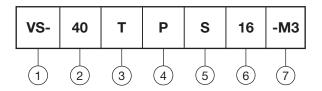


Fig. 9 - Thermal Impedance Z<sub>thJC</sub> Characteristics

### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

**2** - Current rating (40 = 40 A)

3 - Circuit configuration:

T = thyristor

4 - Package:

P = TO-247AC 3L

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage rating (16 = 1600 V)

7 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

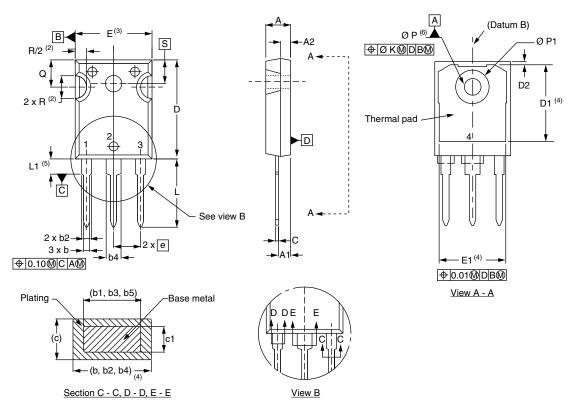
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-40TPS16-M3	25	500	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96138</u>				
Part marking information	www.vishay.com/doc?95007			



### **TO-247AC 3L**

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254		)10	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension Q



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